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(71) Applicant (for all designated States except US):
**HEWLETT-PACKARD DEVELOPMENT COM-
PANY, L.P.** [US/US]; 20555 S.H. 249, HOUSTON, TX
77070 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): **RUDIN, John**,
Christopher [GB/GB]; 85 Kennington Avenue, Bristol
BS7 9EX (GB).

(74) Agent: **MARSH, David, John**; Hewlett-Packard Limited,
Intellectual Property Section, Filton Road, Stoke Gifford,
Bristol BS34 8QZ (GB).

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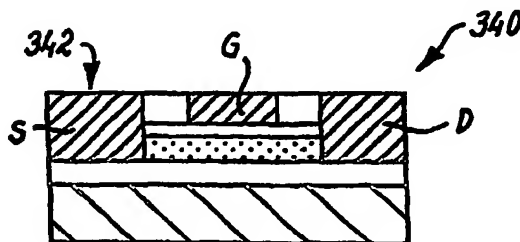
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(54) Title: A TRANSISTOR DEVICE WITH METALLIC ELECTRODES AND A METHOD FOR USE IN FORMING SUCH A
DEVICE



(57) Abstract: A transistor device having a metallic source electrode, a metallic drain electrode, a metallic gate electrode and a channel in a deposited semiconductor material, the transistor device comprising: a first layer comprising the metallic gate electrode, a first metal portion of the metallic source electrode and a first metal portion of the metallic drain electrode; a second layer comprising a second metal portion of the metallic source electrode, a second metal portion of the metallic drain electrode, the deposited semiconductor material and dielectric material between the semiconductor material and the metallic gate electrode; and a third layer comprising a substrate, wherein the first, second and third layers are arranged in order such that the second layer is positioned between the first layer and the third layer.

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